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## SEMICONDUCTOR PHYSICS

- 112001 **Compositional dependence of Raman frequencies in  $\text{Si}_x\text{Ge}_{1-x}$  alloys (5 pages)**  
Zheng Wenli and Li Tinghui
- 112002 **The chemisorption of Mg on the Si (100)-(2 × 1) surface (4 pages)**  
Zhang Fang, Li Wei, and Wei Shuyi
- 112003 **Acetic acid gas sensors based on  $\text{Ni}^{2+}$  doped ZnO nanorods prepared by using the solvothermal method (6 pages)**  
Cheng Zhiming, Zhou Sumei, Chen Tongyun, Dong Yongping, Zhang Wangbing, and Chu Xiangfeng

## SEMICONDUCTOR MATERIALS

- 113001 **Characterization of electrical properties of AlGaN/GaN interface using coupled Schrödinger and Poisson equation (8 pages)**  
S. Das, A. K. Panda, and G. N. Dash
- 113002 **Low threading dislocation density in GaN films grown on patterned sapphire substrates (4 pages)**  
Liang Meng, Wang Guohong, Li Hongjian, Li Zhicong, Yao Ran, Wang Bing, Li Panpan, Li Jing, Yi Xiaoyan, Wang Junxi, and Li Jinmin
- 113003 **Preparation and properties of polycrystalline silicon seed layers on graphite substrate (4 pages)**  
Li Ning, Chen Nuofu, Bai Yiming, and He Haiyang
- 113004 **Preparation of rare-earth element doped  $\text{Mg}_2\text{Si}$  by FAPAS (5 pages)**  
Wang Liqi, Meng Qingsen, and Fan Wenhao

## SEMICONDUCTOR DEVICES

- 114001 **Fabrication of SiC nanowire thin-film transistors using dielectrophoresis (6 pages)**  
Dai Zhenqing, Zhang Liying, Chen Changxin, Qian Bingjian, Xu Dong, Chen Haiyan, Wei Liangming, and Zhang Yafei
- 114002 **A simulation study on a novel trench SJ IGBT (5 pages)**  
Wang Bo, Tan Jingfei, Zhang Wenliang, Chu Weili, and Zhu Yangjun
- 114003 **A new short-anoded IGBT with high emission efficiency (4 pages)**  
Chen Weizhong, Zhang Bo, Li Zehong, Ren Min, and Li Zhaoji
- 114004 **A SPICE model for a phase-change memory cell based on the analytical conductivity model (5 pages)**  
Wei Yiqun, Lin Xinnan, Jia Yuchao, Cui Xiaole, He Jin, and Zhang Xing
- 114005 **12.5 Gb/s carrier-injection silicon Mach-Zehnder optical modulator (3 pages)**  
Chen Hongtao, Ding Jianfeng, and Yang Lin

(Continued on inside back cover)

## SEMICONDUCTOR INTEGRATED CIRCUITS

- 115001 **CMOS analog baseband circuitry for an IEEE 802.11 b/g/n WLAN transceiver (7 pages)**  
Gong Zheng, Chu Xiaojie, Lei Qianqian, Lin Min, and Shi Yin
- 115002 **Design of low noise class D amplifiers using an integrated filter (5 pages)**  
Wang Haishi and Zhang Bo
- 115003 **Switched-capacitor multiply-by-two amplifier with reduced capacitor mismatches sensitivity and full swing sample signal common-mode voltage (7 pages)**  
Xu Xinnan, Yao Suying, Xu Jiangtao, and Nie Kaiming
- 115004 **Pulse swallowing frequency divider with low power and compact structure (4 pages)**  
Gao Haijun, Sun Lingling, Cai Chaobo, and Zhan Haiting
- 115005 **Design of a dual-channel multi-mode GNSS receiver with a  $\Sigma\Delta$  fractional- $N$  synthesizer (7 pages)**  
Long Qiang, Zhuang Yiqi, Yin Yue, Li Le, Wang Jin, Li Zhenrong, Liu Qiankun, and Wang Lei
- 115006 **A programmable gain amplifier with digitally assisted DC offset calibration for a direct-conversion WLAN receiver (5 pages)**  
Yao Xiaocheng, Gong Zheng, and Shi Yin
- 115007 **Millimeter-wave fixed-tuned subharmonic mixers with planar Schottky diodes (5 pages)**  
Yao Changfei, Zhou Ming, Luo Yunsheng, Wang Yigang, and Xu Conghai
- 115008 **Design of ternary low-power Domino JKL flip-flop and its application (5 pages)**  
Wang Pengjun, Yang Qiankun, and Zheng Xuesong
- 115009 **An embeddable SOC real-time prediction technology for TDDB (5 pages)**  
Xin Weiping, Zhuang Yiqi, and Li Xiaoming
- 115010 **A digital background calibration algorithm of a pipeline ADC based on output code calculation (5 pages)**  
Shao Jianjian, Li Weitao, Sun Cao, Li Fule, Zhang Chun, and Wang Zhihua
- 115011 **Design and implementation of an ultra-low power passive UHF RFID tag (6 pages)**  
Shen Jinpeng, Wang Xin'an, Liu Shan, Zong Hongqiang, Huang Jinfeng, Yang Xin, Feng Xiaoxing, and Ge Binjie
- 115012 **A micro-power LDO with piecewise voltage foldback current limit protection (5 pages)**  
Wei Hailong, Liu Youbao, Guo Zhongjie, and Liao Xue
- 115013 **A 1.8 V low-power 14-bit 20 Msps ADC with 11.2 ENOB (8 pages)**  
Cai Hua

## SEMICONDUCTOR TECHNOLOGY

- 116001 **Planarization properties of an alkaline slurry without an inhibitor on copper patterned wafer CMP (5 pages)**  
Wang Chenwei, Liu Yuling, Tian Jianying, Niu Xinhuan, Zheng Weiyan, and Yue Hongwei